

# ST13005

## High voltage fast-switching NPN power transistor

#### Datasheet - production data

### Features

- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

### **Applications**

- Electronic ballast for fluorescent lighting
- Switch mode power supplies

## Description

This device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining a wide RBSOA.



#### Figure 1. Internal schematic diagram



Order code	Marking <sup>(1)</sup>	Package	Packaging
	13005 A		
	13005 C		
ST13005	13005 D	TO-220	Tube
	13005 E		
	13005 F		

1. Product is pre-selected in DC current gain (group A, C, D, E and F). STMicroelectronics reserves the right to ship either groups according to production availability. Please contact your nearest STMicroelectronics sales office for delivery details.

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This is information on a product in full production.

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# 1 Electrical ratings

Symbol	Parameter	Value	Unit
V <sub>CES</sub>	Collector-emitter voltage (V <sub>BE</sub> = 0)	700	V
V <sub>CEO</sub>	Collector-emitter voltage $(I_B = 0)$	400	V
V <sub>EBO</sub>	Emitter-base voltage ( $I_C = 0$ )	9	V
۱ <sub>C</sub>	Collector current	4	А
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5 ms)	8	А
Ι <sub>Β</sub>	Base current	2	А
I <sub>BM</sub>	Base peak current (t <sub>P</sub> < 5 ms)	4	А
P <sub>TOT</sub>	Total dissipation at T <sub>c</sub> ≤25 °C	75	W
T <sub>STG</sub>	Storage temperature	- 65 to 150	°C
Τ <sub>J</sub>	Max. operating junction temperature	150	°C

#### Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thj-case</sub>	Thermal resistance junction-case max	1.7	°C/W
R <sub>thj-amb</sub>	Thermal resistance junction-amb max	62.5	°C/W



## 2 Electrical characteristics

 $T_{case}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 700 V V <sub>CE</sub> = 700 V T <sub>C</sub> =125 °C			1 5	mA mA
	(*BE - 0)	V <sub>CE</sub> = 700 V I <sub>C</sub> =125 C			5	IIIA
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 9 V			1	mA
V <sub>CEO(sus)</sub> <sup>(1)</sup>	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> =10 mA	400			V
		I <sub>C</sub> = 1 A I <sub>B</sub> = 0.2 A			0.5	V
V <sub>CE(sat)</sub> <sup>(1)</sup>	Collector-emitter saturation voltage	$I_{\rm C} = 2  {\rm A}$ $I_{\rm B} = 0.5  {\rm A}$			0.6	V
0 = (000)	saturation voltage	$I_{\rm C} = 4  {\rm A}$ $I_{\rm B} = 1  {\rm A}$			1	V
V <sub>BE(sat)</sub> <sup>(1)</sup>	Base-emitter saturation	I <sub>C</sub> = 1 A I <sub>B</sub> = 0.2 A			1.2	V
VBE(sat)	voltage	$I_{\rm C} = 2 \mbox{ A}$ $I_{\rm B} = 0.5 \mbox{ A}$			1.6	V
		$I_{\rm C} = 1 \ {\rm A}$ $V_{\rm CE} = 5 \ {\rm V}$				
		Group A	15		32	
	DC current gain	Group C	16		22	
h <sub>FE</sub> <sup>(1)(2)</sup>		Group D	21		27	
		Group E	26		32	
		Group F	31		37	
		I <sub>C</sub> = 2 A V <sub>CE</sub> = 5 V	8		40	
	Resistive load	I <sub>C</sub> = 2 A V <sub>CC</sub> = 125 A				
t <sub>s</sub>	Storage time	I <sub>B1</sub> = - I <sub>B2</sub> =0.4 A	1.5		3	μs
t <sub>f</sub>	Fall time	t <sub>p</sub> = 30 μs		0.2		μs

 Table 4.
 Electrical characteristics

1. Pulse test: pulse duration = 300  $\mu$ s, duty cycle  $\leq 2$  %.

2. Product is pre-selected in DC current gain (group A, C, D, E and F). STMicroelectronics reserves the right to ship either groups according to production availability. Please contact your nearest STMicroelectronics sales office for delivery details



### 2.1 Electrical characteristics (curves)



Figure 2. Safe operating area Figure 3. Derating curve







Figure 6. Collector-emitter saturation Figure 7. Ba voltage vol

Base-emitter saturation voltage



 $R_{BB} = 0 \Omega$ 

 $V_{BE(off)} = -5V$ 

6 I<sub>C</sub>(A)

#### Figure 8. Inductive load fall time Figure 9. Inductive load storage time GC69450 GC70840 t<sub>f</sub>(ns) $t_s(\mu s)$ $V_{Clamp} = 200 V$ h<sub>FE</sub> =5



## 3 Figure 11. Resistive load storage time

4 5

T<sub>J</sub> = 125 °C

 $\overline{}$ T<sub>J</sub> =25 °C

1 2

1

0.1

0



#### Figure 12. Reverse biased safe operating area

t<sub>f</sub>(ns)

600

500

300

200

100

0



## 2.2 Test circuits





Figure 14. Resistive load switching test circuit





## **3** Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK<sup>®</sup> is an ST trademark.



Table 5.	10-220 type A mechanica	al data			
Dim.		mm.			
	Min.	Тур.	Max.		
А	4.40		4.60		
b	0.61		0.88		
b1	1.14		1.70		
С	0.48		0.70		
D	15.25		15.75		
D1		1.27			
E	10		10.40		
е	2.40		2.70		
e1	4.95		5.15		
F	1.23		1.32		
H1	6.20		6.60		
J1	2.40		2.72		
L	13		14		
L1	3.50		3.93		
L20		16.40			
L30		28.90			
ØР	3.75		3.85		
Q	2.65		2.95		

Table 5.TO-220 type A mechanical data









# 4 Revision history

#### Table 6.Document revision history

Date	Revision	Changes
21-Jun-2004	6	
22-Aug-2007	7	Updated mechanical data according to PCN APM-PWR/07/2804
12-Oct-2007	8	Updated marking in Table 1
15-Feb-2012	9	<ul> <li>Updated marking in <i>Table 1</i></li> <li>Inserted: <i>Table 3</i></li> <li>Modified: h<sub>FE</sub> in <i>Table 4</i></li> <li>Updated mechanical data</li> </ul>
15-May-2012	10	Updated marking in Table 1 and 4



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